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# N-Channel 100 V (D-S) MOSFET

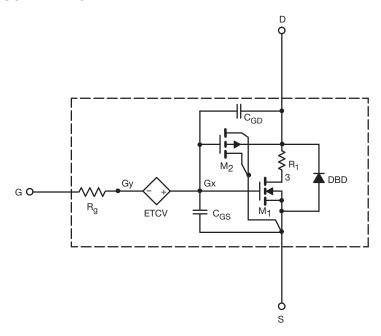
### **DESCRIPTION**

The attached SPICE model describes the typical electrical characteristics of the N-Channel vertical DMOS. The subcircuit model is extracted and optimized over the -55 °C to +150 °C temperature ranges under the pulsed -20 V to +20 V gate drive. The saturated output impedance is best fit at the gate bias near the threshold voltage. A novel gate-to-drain feedback capacitance network is used to model the gate charge characteristics while avoiding convergence difficulties of the switched  $C_{\rm gd}$  model. All model parameter values are optimized to provide a best fit to the measured electrical data and are not intended as an exact physical interpretation of the device.

### **CHARACTERISTICS**

- N-channel vertical DMOS
- Macro model (subcircuit model)
- Level 3 MOS
- · Apply for both linear and switching application
- Accurate over the -55 °C to +150 °C temperature range
- Model the gate charge

#### SUBCIRCUIT MODEL SCHEMATIC



#### Note

This document is intended as a SPICE modeling guideline and does not constitute a commercial product datasheet. Designers should refer
to the appropriate datasheet of the same number for guaranteed specification limits



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<b>SPECIFICATIONS</b> (T <sub>C</sub> = 25 °C, unless otherwise noted)					
PARAMETER	SYMBOL	TEST CONDITIONS	SIMULATED DATA	MEASURED DATA	UNIT
Static					
Gate-source threshold voltage	V <sub>GS(th)</sub>	$V_{DS} = V_{GS}, I_D = 250 \mu A$	2.1	-	V
Drain-source on-state resistance <sup>a</sup>	R <sub>DS(on)</sub>	$V_{GS} = 10 \text{ V}, I_D = 2 \text{ A}$	0.125	0.124	Ω
		$V_{GS} = 4.5 \text{ V}, I_D = 1 \text{ A}$	0.141	0.138	
Forward transconductance <sup>a</sup>	9fs	V <sub>DS</sub> = 20 V, I <sub>D</sub> = 2 A	8	12	S
Dynamic <sup>b</sup>					
Input capacitance	C <sub>iss</sub>	V <sub>DS</sub> = 50 V, V <sub>GS</sub> = 0 V, f = 1 MHz	288	290	pF
Output capacitance	Coss		27	26	
Reverse transfer capacitance	C <sub>rss</sub>		5	5	
Total gate charge	Qg	$V_{DS} = 50 \text{ V}, V_{GS} = 10 \text{ V}, I_D = 0.5 \text{ A}$	4.7	4.7	nC
		V <sub>DS</sub> = 50 V, V <sub>GS</sub> = 4.5 V, I <sub>D</sub> = 0.5 A	2.2	2.2	
Gate-source charge	Q <sub>gs</sub>		0.7	1	
Gate-drain charge	$Q_{gd}$		0.8	0.5	
Drain-source body diode characteristics					
Body diode voltage	$V_{SD}$	I <sub>S</sub> = 1.6 A	0.84	0.8	V
Body diode reverse recovery time	t <sub>rr</sub>	I <sub>F</sub> = 1.6 A di/dt = 100 A/μs, T <sub>J</sub> = 25 °C	21	21	ns
Body diode reverse recovery charge	Q <sub>rr</sub>		18	21	nC
Reverse recovery fall time	ta		17	19	ns
Reverse recovery rise time	t <sub>b</sub>		4	2	

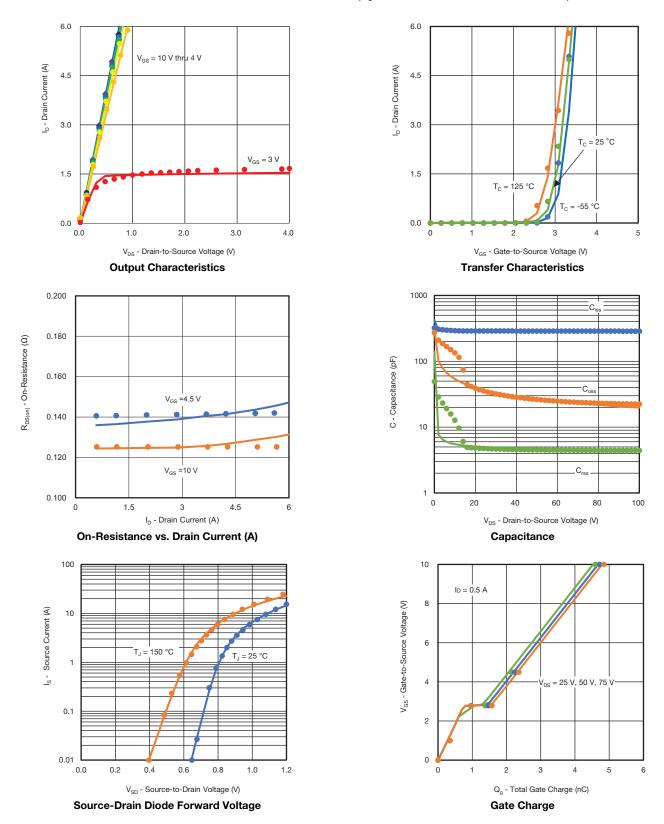
#### Notes

- a. Pulse test; pulse width  $\leq 300~\mu s,~duty~cycle \leq 2~\%$
- b. Guaranteed by design, not subject to production testing

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## **COMPARISON OF MODEL WITH MEASURED DATA** ( $T_J = 25~^{\circ}C$ , unless otherwise noted)



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